#### Computational Chemistry and Materials Modeling

# Lecture 6 Computational Chemistry of Crystals

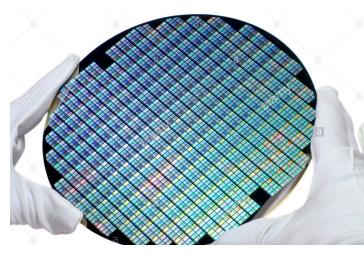
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#### What are the examples of crystals?

Minerals (insulating)



Semiconductors

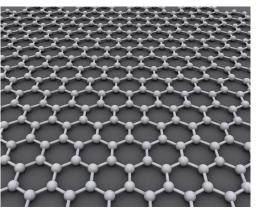




Metals and alloys

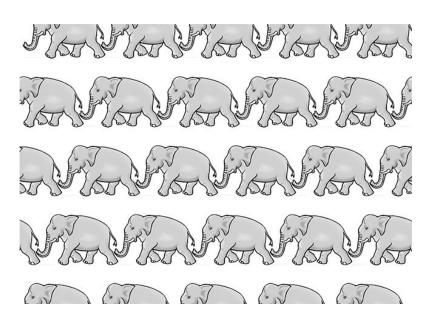






#### What is the main difference of crystals from molecules?

- Translational symmetry the atomic structure is repeated infinitely in three dimensions
- The number of symmetries is limited





Evgraf Fedorov, mathematician, crystallographer and mineralogist derived 230 symmetry space groups The Symmetry of Regular Systems of Figures, 1891

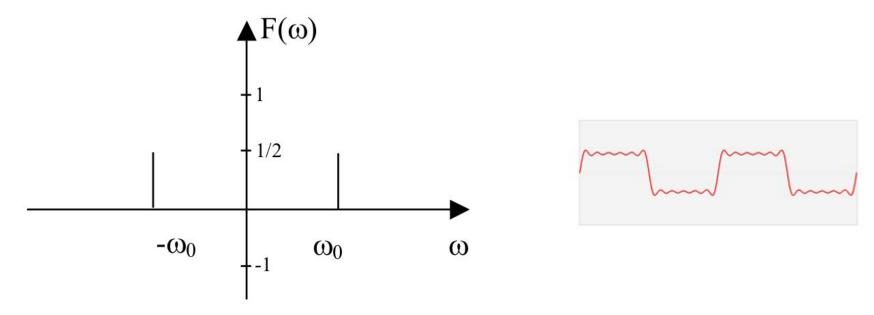
Problem: How to represent the infinite system?

#### Fourier transform: functions of time

The Fourier transform F of a function f(t) is a function  $F(\omega)$  in frequency domain, and is defined as:

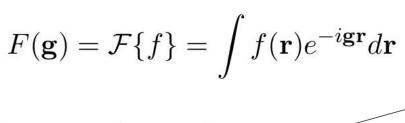
$$F(\omega) = \mathcal{F}\{f\} = \int_{-\infty}^{\infty} f(t)e^{-i\omega t}dt$$

Fourier transform of  $cos(\omega_0 t)$ :



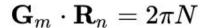
#### Fourier transform: functions of space

The Fourier transform F of a function f (r) is a function F (g) in g space domain:



$$\mathbf{R} = n_1 \mathbf{a_1} + n_2 \mathbf{a_2} + n_3 \mathbf{a_3}$$

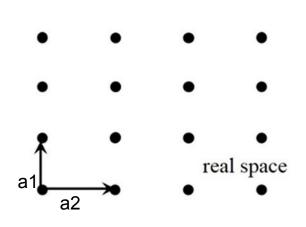
$$\mathbf{G} = m_1 \mathbf{b_1} + m_2 \mathbf{b_2} + m_3 \mathbf{b_3}$$

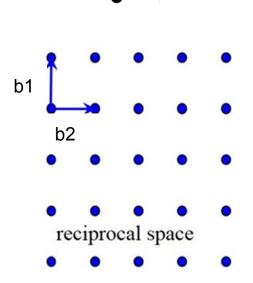


$$\mathbf{b}_1 = 2\pi rac{\mathbf{a}_2 imes \mathbf{a}_3}{\mathbf{a}_1 \cdot (\mathbf{a}_2 imes \mathbf{a}_3)}$$

$$\mathbf{b}_2 = 2\pi \frac{\mathbf{a}_3 \times \mathbf{a}_1}{\mathbf{a}_2 \cdot (\mathbf{a}_3 \times \mathbf{a}_1)}$$

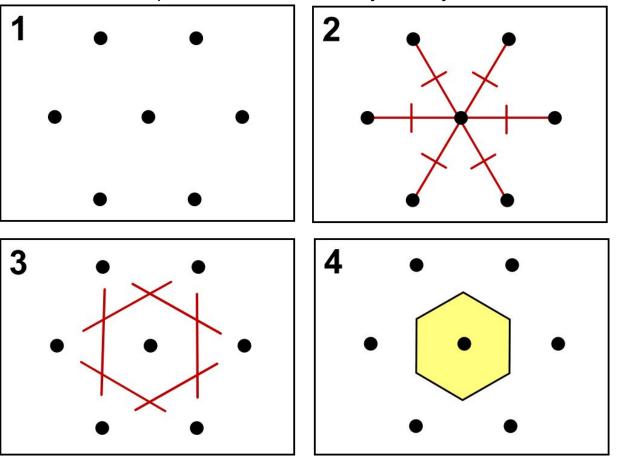
$$\mathbf{b}_3 = 2\pi rac{\mathbf{a}_1 imes \mathbf{a}_2}{\mathbf{a}_3 \cdot (\mathbf{a}_1 imes \mathbf{a}_2)}$$



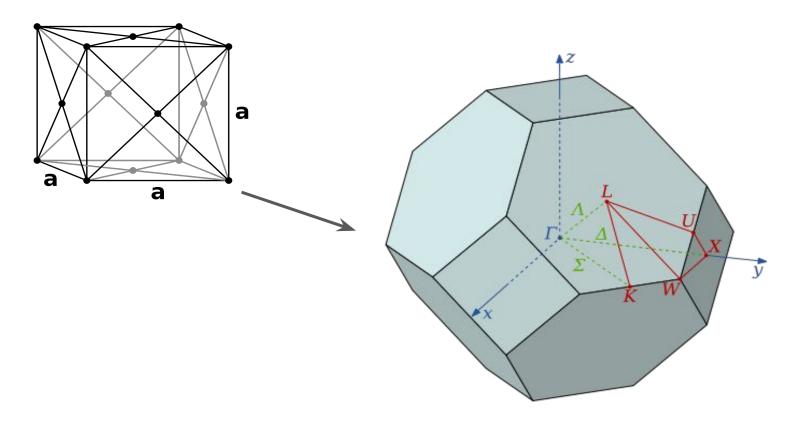


#### Brillouin zone and Wigner seitz cell

- Primitive cell cell with minimal volume, infinite number of possibilities
- First Brillouin zone (BZ) is a primitive cell in reciprocal space with the symmetry of the reciprocal lattice
- Wigner-seitz cell the primitive cell with the symmetry of the Bravais lattice



#### First BZ for FCC lattice



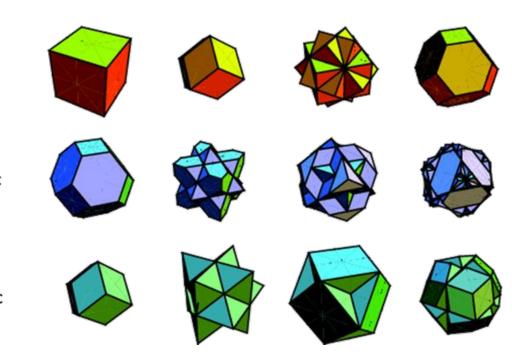
- The reciprocal lattice for FCC lattice is BCC
- Γ is the center of Brillouin zone
- High-symmetry directions are called with Greek letters (<u>see here</u>), high symmetry points with Latin
- Fundamental domain of BZ is often called irreducible Brillouin zone (IBZ)

### **Understanding Brillouin zones**

First 27 BZ for 2D square lattice

SC FCC BCC

First 4 BZ for 3D lattices:



All BZ are of equal volume

#### Electrons in periodic potential of ions

$$V(\mathbf{r}+\mathbf{R})=V(\mathbf{r})$$
 
$$V(\mathbf{r})=\sum_{\mathbf{G}}V_{\mathbf{G}}\mathrm{e}^{\mathrm{i}\mathbf{G}.\mathbf{r}},$$
 where G is a set of vectors and the V<sub>G</sub> are Fourier coefficients

#### **Bloch theorem for periodic systems**

**Theorem:** In periodic system, one-electron wavefunction can be chosen to be a plane wave times the periodicity of the Bravais lattice:



Felix Bloch Nobel prize in 1952

$$\phi_{\mathbf{k},n}(\mathbf{r}) = u_{\mathbf{k},n}(\mathbf{r})e^{i\mathbf{k}\mathbf{r}}$$

- **k** new quantum number, vector in **reciprocal space!**
- n is band number from the solution of reduced spectral problem with PBC
- only one reciprocal cell -> finite volume problem
- eikr invariant with respect k = k+G, where G is translation vector

### Plane wave basis set for periodic part, $u_k(r)$

$$u_{\mathbf{k}}(\mathbf{r}) = \sum_{\mathbf{G}} c_{\mathbf{G}} \exp[i\mathbf{G} \cdot \mathbf{r}],$$

**G** is translation vector of reciprocal lattice The periodic part is a sum of plane waves

$$\phi_{\mathbf{k}}(\mathbf{r}) = \sum_{\mathbf{G}} c_{\mathbf{k}+\mathbf{G}} \exp[i(\mathbf{k} + \mathbf{G})\mathbf{r}].$$

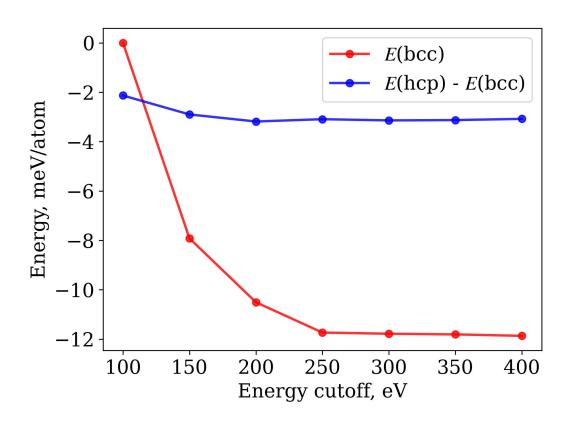
$$E = \frac{h^2}{2m} |\mathbf{k} + \mathbf{G}|^2$$
.  $E_{\text{cut}} = \frac{h^2}{2m} G_{\text{cut}}^2$ .

$$\phi_{\mathbf{k}}(\mathbf{r}) = \sum_{|\mathbf{G}+\mathbf{k}| < G_{\text{cut}}} c_{\mathbf{k}+\mathbf{G}} \exp[i(\mathbf{k}+\mathbf{G})\mathbf{r}].$$

Typical  $E_{\rm cut}$  of 500 eV corresponds to **0.5** Å distance in real space.

- In real crystal we do not expect too large energies
- Therefore we can omit plane waves with large G
- In VASP <u>ENCUT</u>
   parameter
- Important to perform all calculations at the same E-cut
- Check convergence!

#### Convergence with respect to e-cut



Convergence of the energy cut-off for bcc Li and energy difference using the PBE functional and a 8x8x8 k-point grid for conventional cell.

- Make all calculations at fixed cut-off
- The absolute energy has little sense, use differences
- Check convergence for property of interest

#### **Bloch theorem for Kohn-Sham equations**

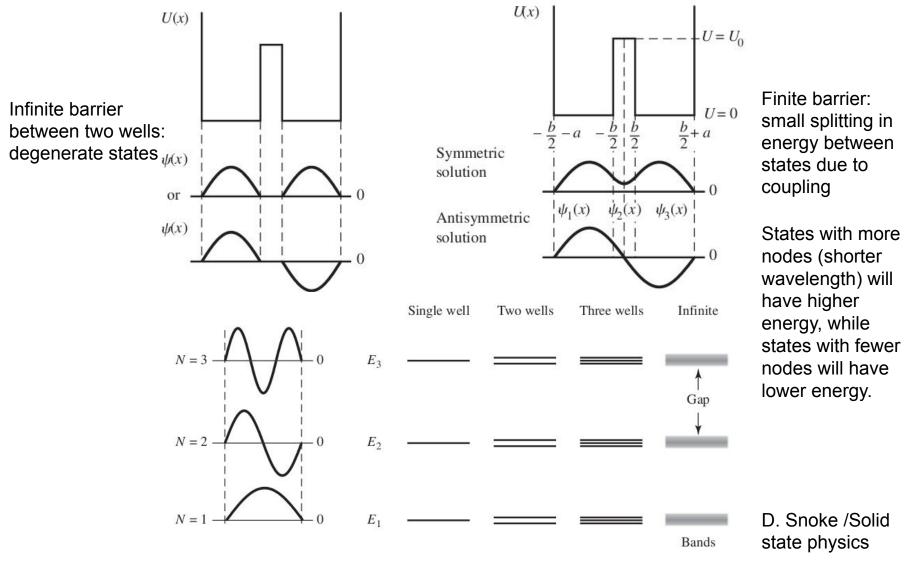
$$\left[ -\frac{1}{2} \nabla^2 + V_{\text{tot}}(\mathbf{r}) \right] \phi_n(\mathbf{r}) = \varepsilon_n \phi_n(\mathbf{r})$$

Kohn-Sham equations can be solved separately for each point at k-space

$$\left[ -\frac{1}{2} (\nabla + i\mathbf{k})^2 + V_{\text{tot}}(\mathbf{r}) \right] u_{n,\mathbf{k}}(\mathbf{r}) = \varepsilon_{n,\mathbf{k}} u_{n,\mathbf{k}}(\mathbf{r})$$

- In analogy to the particle in the box there are infinite number of solutions n,  $u_{n\mathbf{k}+\mathbf{G}} = u_{n\mathbf{k}}$  where n is the number of band
  - o but now, number of occupied bands is finite
- The energy of electron now is a function of **k** for each n,  $\varepsilon_n(\mathbf{k})$  this is called band dispersion

# Simple picture for band formation in quantum wells (Kronig-Penney model)



## 1D case, infinite chain of H atoms with non-interacting electrons

$$\psi(k) = \sum_{n=1}^N e^{ikna}\phi_n$$
 with  $0 \leq |k| \leq \frac{\pi}{a}$ , a - interatomic distance,  $\phi$  - atomic orbital

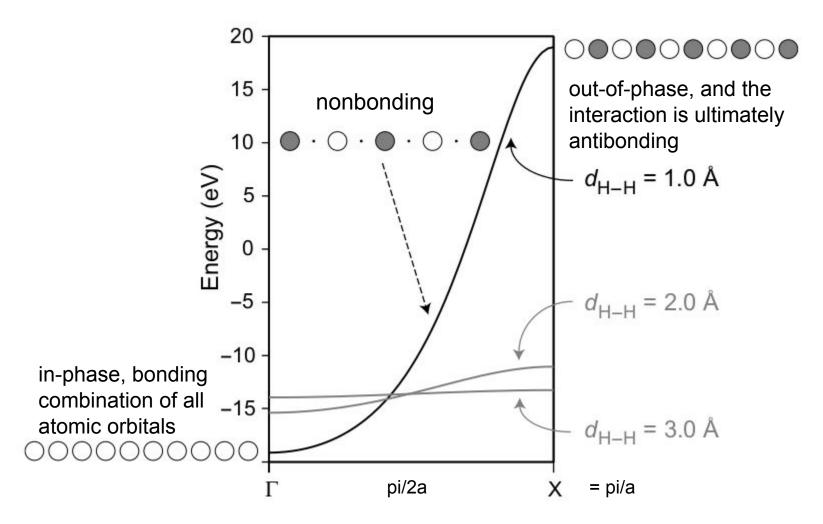
$$\psi(0)=\sum_{n=1}^N\phi_n=\phi_1+\phi_2+\phi_3+\phi_4+\phi_5\dots$$
, At k = 0, also known as  $\Gamma$ 

$$\psi\left(\frac{\pi}{a}\right) = \sum_{n=1}^{N} e^{i\pi n} \phi_n = -\phi_1 + \phi_2 - \phi_3 + \phi_4 - \phi_5 \dots$$
, At k =  $\pi/a$ , also known as X

The same procedure for intermediate k values

$$E(k) = \frac{\langle \psi(k) | \mathcal{H} | \psi(k) \rangle}{\langle \psi(k) | \psi(k) \rangle}$$

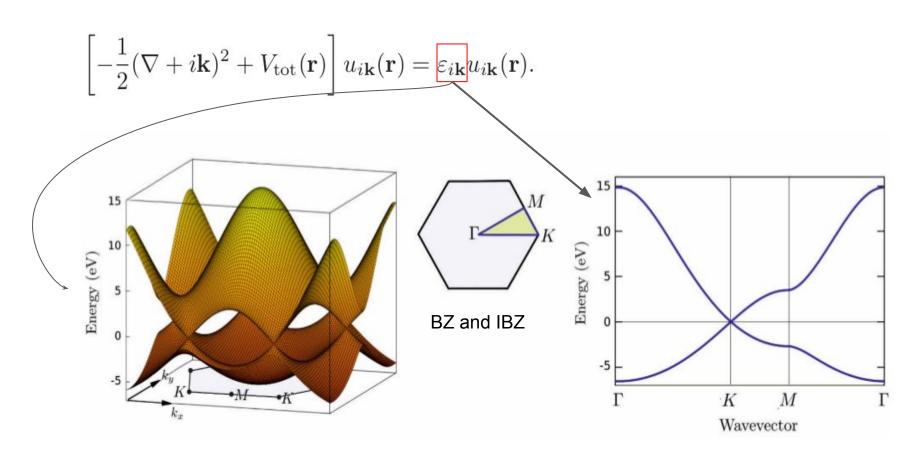
#### Band structure for hydrogen chain



First Brillouin zone in 1D case

Dronskowski

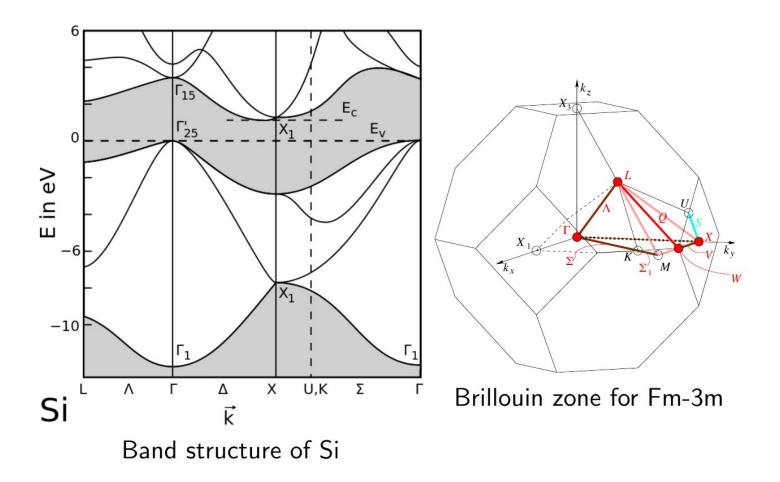
#### **Example of band structure for graphene**



one-dimensional cross-sections is the most common way to visualize bands

Change of energy along high-symmetry direction

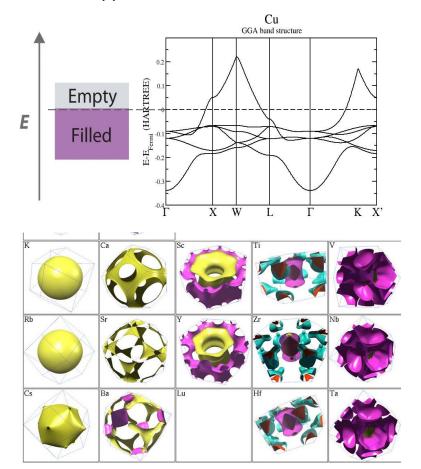
#### **Example of band structure for silicon**



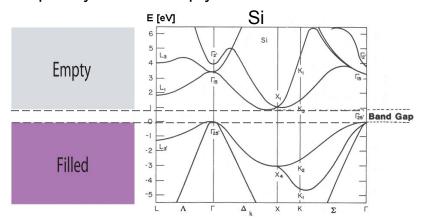
#### **Ground state and Fermi surface**

The ground state of N electrons is obtained by filling one-electron bands with energies  $\varepsilon_n(\mathbf{k})$  up to the Fermi energy. Some bands are fully filled, the others are empty

Case 1: The band is partially filled or overlapped



Case 2: The band is either completely filled or empty



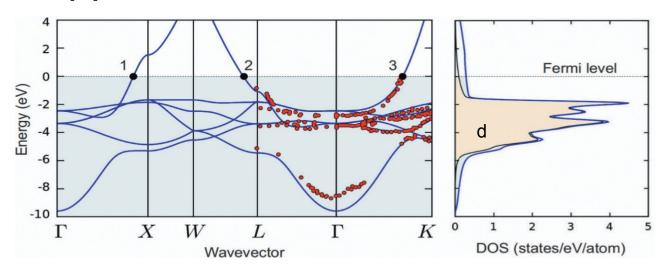
No Fermi surface for band gap materials! -> definition for metals

#### **Density of states**

$$DOS(E) = \sum_{n} \int_{BZ} \frac{d\mathbf{k}}{\Omega_{BZ}} \delta(E - \varepsilon_{n,\mathbf{k}})$$

Cu [Ar] 4s1 3d10 FCC lattice with 1 atom

11 Kohn-Sham electrons



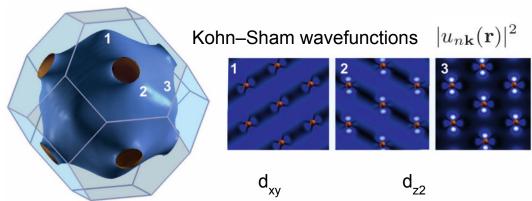
The parabolic behaviour in L-Γ-K region resembles free electron gas, however it is interrupted by spaghetti-like d states

The red discs are from the experimental angle-resolved photoemission data - The Kohn-Sham eigenvalues has some physical reality

Significant differences between states across the Fermi surface.

Fermi Surface

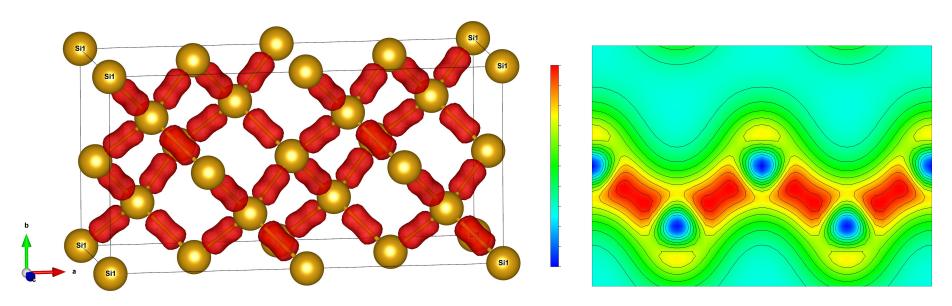
from Giustino



#### **Charge density**

$$n(\mathbf{r}) = \sum_{n} \int_{BZ} \frac{d\mathbf{k}}{\Omega_{BZ}} f_{n,\mathbf{k}} |u_{n,\mathbf{k}}|^{2}$$

for VASP users plot <a href="CHGCAR">CHGCAR</a> file in VESTA



Charge density for Silicon

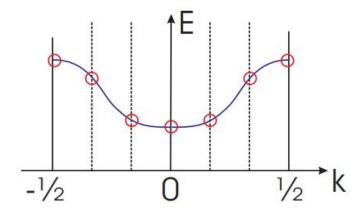
Plot charge density difference for fixed atomic positions

#### **Discussion**

- What is the difference of Brillouin zone from other primitive cells in the reciprocal space?
- Why do we need smearing of a Fermi-level?
- Why antisymmetric solution has higher energy compared to the symmetric one?
- What is the difference of real crystal from ideal periodic crystal?

#### k-point sampling

$$E = \frac{V_c}{8\,\pi^3} \int d^3k \,\, \varepsilon(\mathbf{k})$$



- For continuous function very efficient integration can be done using only several k-points
- k-point grid N<sub>1</sub>xN<sub>2</sub>xN<sub>3</sub> in 3D

Monkhorst-Pack - regular equispaced mesh

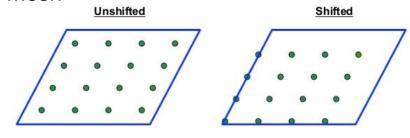


TABLE 3.1 Approximations to the Integral  $\int_{-1}^{1} \frac{\pi x}{2} \sin(\pi x) dx = 1$  Using the Trapezoidal and Legendre Quadrature Methods

N	Trapezoidal Method	Legendre Quadrature Method
2	0.6046	1.7605
3	0.7854	0.8793
4	0.8648	1.0080
5	0.9070	0.9997

Sholl p.54

#### **Choosing k-points mesh**

How to choose N<sub>1</sub>,N<sub>2</sub>, N<sub>3</sub>?

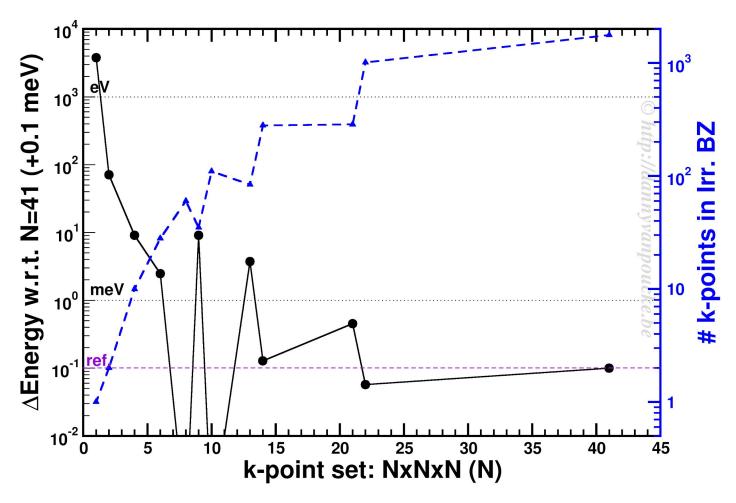
Commonly the following rule of thumb applies:

$$N_1:N_2:N_3 = |b_1|:|b_2|:|b_3|$$

where **b**<sub>i</sub> are the reciprocal lattice vectors.

- for VASP k-points are provided in <u>KPOINTS</u> file
- For automatic generation use <u>KSPACING</u> tag
- check convergence up to k-spacing of 0.05 A<sup>-1</sup>!
  - k-spacing 0.5 A<sup>-1</sup> risk of large errors

#### Convergence with respect to k-grid



K-point convergence of alpha-Cerium using the PBE functional and ENCUT=500 eV. https://dannyvanpoucke.be/vasp-tutor-convergence-testing-en/

#### **Smearing at Fermi level**

$$E = \sum_{i} \int_{BZ} \frac{d\mathbf{k}}{\Omega_{BZ}} f_{i\mathbf{k}} \varepsilon_{i\mathbf{k}} - \left[ E_{H} + \int d\mathbf{r} V_{xc}(\mathbf{r}) n(\mathbf{r}) - E_{xc} \right] \qquad \mathbf{f}_{i\mathbf{k}} = \frac{1}{e^{(\epsilon_{i\mathbf{k}} - \mu)/\sigma} + 1} \quad \mathbf{Q}^{\epsilon}$$

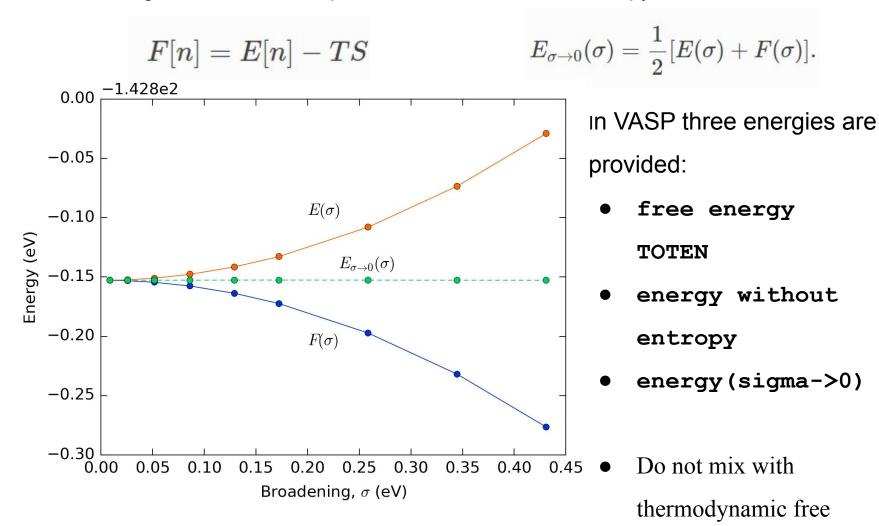
Discontinuity - very large number of k-points Sholl, p. 60 is needed to calculate integrals correctly Cu 1.1 -GGA band structure 1.0 0.9  $\sigma = 0.02$ 0.8 0.7 E-E<sub>Fermi</sub> (HARTREE) 0.4  $\sigma = 0.5$ 0.3 0.2 0.1 0.0 0.2 0.4 0.6 0.8 1.0 1.2 1.4 1.6 1.8 2.0 X W

**Figure 3.3** Fermi Dirac function [Eq. (3.10)] with  $k_0 = 1$  and several values of  $\sigma$ .

- Smearing is needed to make function continuous, <u>ISMEAR</u>
- In VASP: **ISMEAR** chose method for smearing, **SIGMA** the value of smearing
- Check smearing parameter!
- More k-points for metals, density < 0.15 A<sup>-1</sup> (KSPACING)

#### (Electronic) free energy functional

When introducing the *Fermi-Dirac* distribution one effectively considers an equivalent system of non-interacting electrons at a temperature T with electronic entropy S



energy

#### Convergence with respect to k-points and smearing

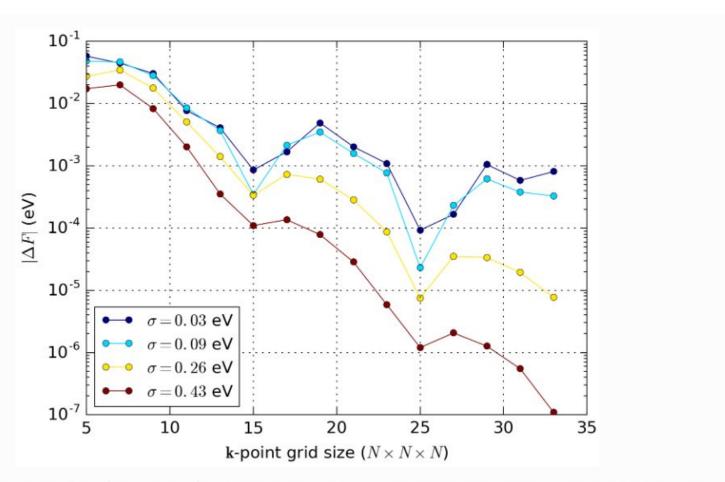


Fig. 105 Convergence of the free energy of bulk Aluminum with respect to the k-point sampling using the Fermi-Dirac occupation function with different broadenings. The free energy difference,  $\Delta F$ , is calculated as the difference between the calculation at the given  ${\bf k}$ -point sampling and one at  $35 \times 35 \times 35$ .

https://docs.quantumatk.com/manual/technicalnotes/occupation\_methods/occupation\_methods.html

#### **Smearing methods**

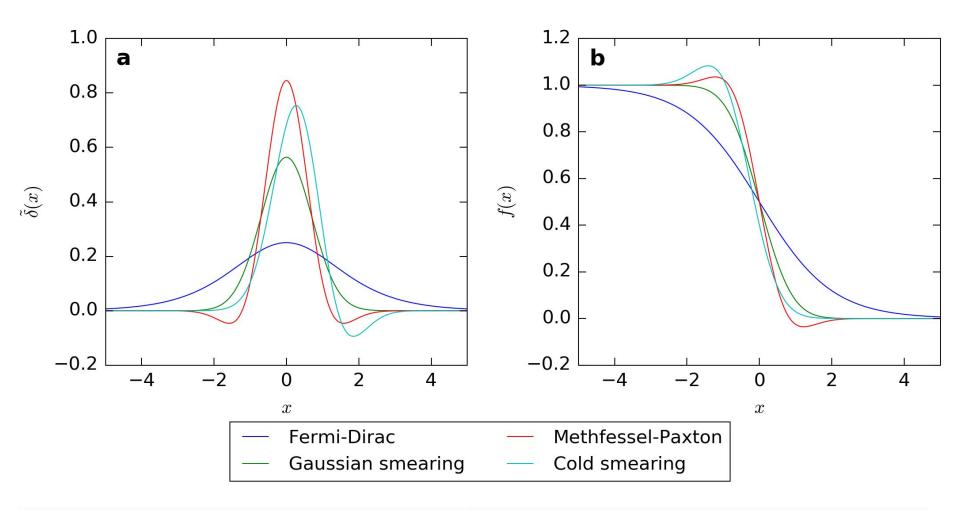
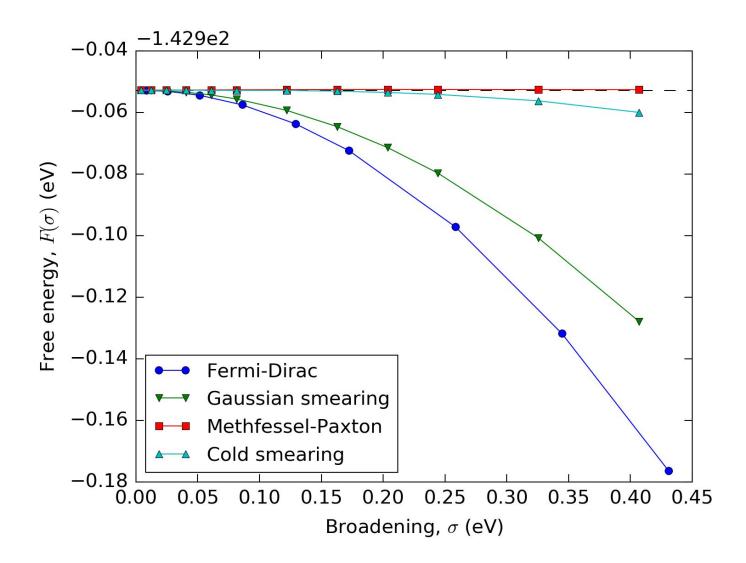
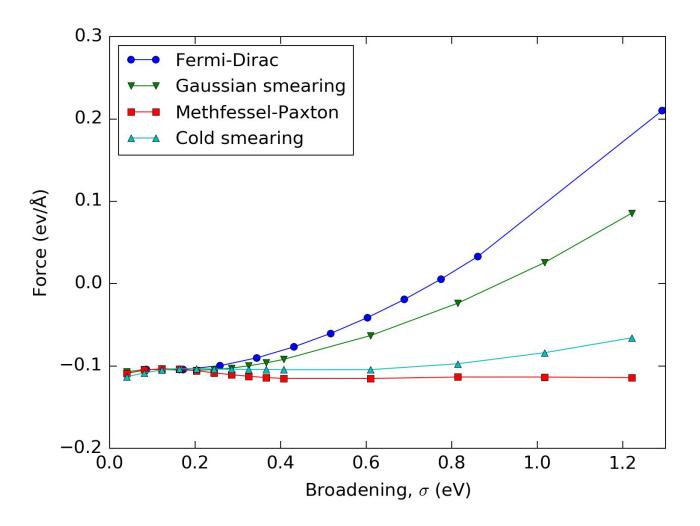


Fig. 107 (a) Plots of the different smeared delta functions,  $\tilde{\delta}(x)$ , and (b) their corresponding occupation functions f(x), shown as functions of  $x=\frac{\epsilon-\mu}{\sigma}$ .

#### **Energy error for different smearing methods**



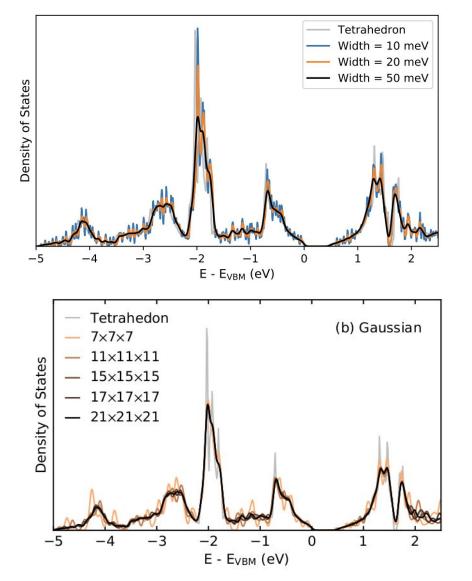
#### Force error for different smearing methods



Force on the outermost atom in a 6 layer Aluminum 111 slab as a function of the broadening using the different occupation methods. In order to keep the different methods comparable, the broadening has been multiplied by 2.117 for all but the Fermi-Dirac distribution.

#### **Smearing of DOS**

https://arxiv.org/pdf/2103.03469.pdf



SIGMA=50 meV

#### Advices on choosing k-grid and smearing

#### K-grids

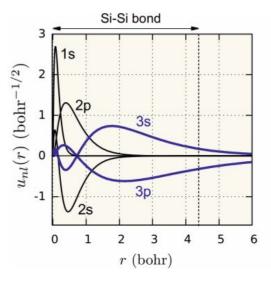
- Use equally spaced grids of points, a shift can reduce number of k-points
- Try Gamma-centered k-grid if you have problem with off-center Monkhorst-Pack
- Use fine grid for DOS
- Use equivalent k-points meshes when comparing different cells

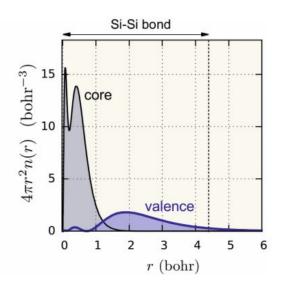
#### Orbital occupation (smearing)

- Systems with a band-gap (semiconductors, insulators, molecules): Use either Fermi-Dirac (fictitious temperatures) or Gaussian smearing (robust) with a low broadening, e.g. around 0.05 0.2 eV (Smaller is better, but the SCF convergence can be long ...).
- **Metals**: Use either *Methfessel-Paxton* or *cold* smearing with as large a broadening as possible as long as the entropy contribution to the free energy remains small. Ensure that you have several empty bands, which is required for convergence
- DOS: tetrahedron smearing with Bl"ochl corrections accurate interpolation for energies and DOS, but may introduce errors in forces (https://arxiv.org/pdf/2103.03469.pdf)

#### Plane-waves for valence and core electrons

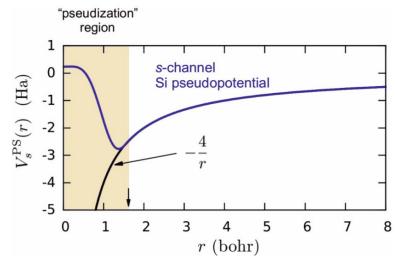
Guistino E1





- The valence electrons distributed mainly between Si atoms
- The core electrons localized near the cores and do not participate in bonding

- To describe core electrons a lot of plane waves are required
  - very computationally demanding!
- Solution: Pseudopotential



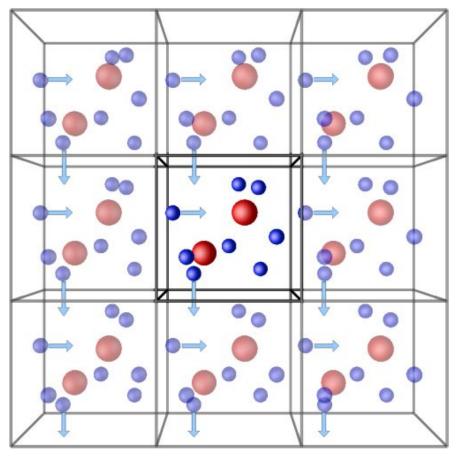
#### **Pseudopotential in DFT codes**

- Hard and soft potentials large and small e-cut
- (<u>POTCAR</u> in VASP)
- PAW projected augmented wave method, See for VASP <u>PAW</u>
   (different number of valence electrons available, <u>sv. pv</u>)
- Vanderbilt USP, norm-conserving
- Check required pseudopotential for your task
  - number of electrons (more for small distances)
  - minimal energy cut-off (if several elements are used, the maximal should be chosen)
- Use the same pseudopotential for all calculations

#### **XC** functional

- PBE the most popular functional for general purpurses; averagely good for any properties
  - PBEsol improves equilibrium properties of densely-packed solids and their surfaces
  - RPBE improves adsorption description
- PBE+U fix delocalization problems of PBE when higher level methods are not available, improves description of strongly correlated systems
- Hybrids PBE0, HSE for strongly correlated systems
  - may be worse than PBE+U
  - very computationally demanding (by 3 orders in plane-wave codes)
- PBE + dispersion corrections for layered materials
  - <u>DFT-D2</u>, <u>DFT-D3</u>, <u>many-body dispersion (MBD) method of Tkatchenko</u>,
     etc

## **Periodic Boundary conditions**



Periodic boundary conditions (PBC) -

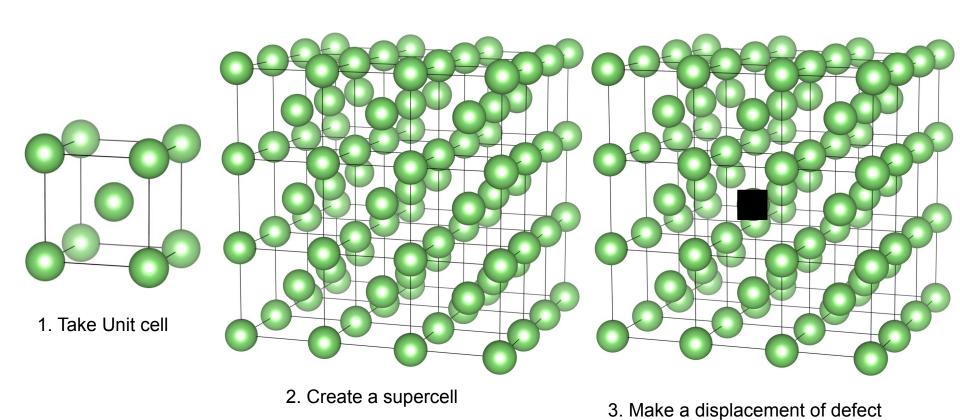
- when an object passes through one side of the unit cell, it reappears on the opposite side with the same velocity.
- Ideally suited for periodic systems

### Keep in mind!

 Any atomic displacements or defects inside the unit cell are replicated infinitely, which may lead to artificial interactions

- The net electrostatic charge of the system must be zero
- Charged defects can considered by adding an homogeneous background charge of opposite sign

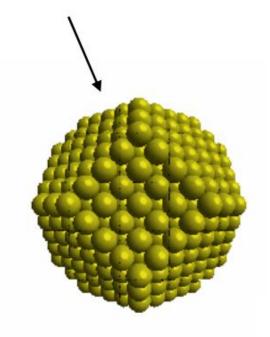
## Supercell approach for non-periodicity



- Remember that large supercell is still affected by PBC conditions
- Check convergence with respect to supercell size

### Free boundary conditions

#### Free cluster



No translation symmetry!

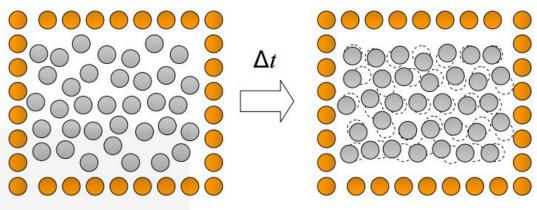
#### Cons:

- non physical electronic states
- levels in the gap
- finite size quantum effects

#### Therefore:

For molecules, clusters, disordered solids in classical MD simulations

Rigid shell, still unphysical, but better than open



## Optimization of atoms in periodic systems

Similar to molecular, see previous lecture

In VASP important parameters:

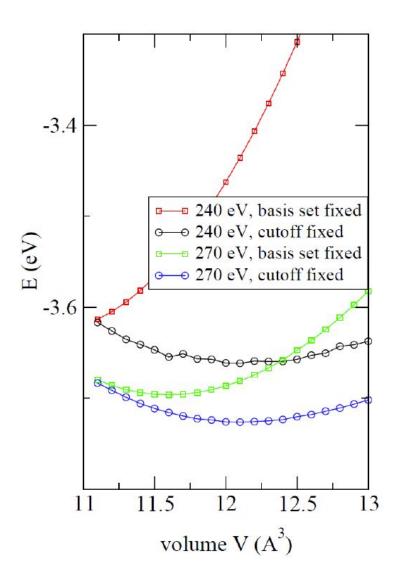
- <u>IBRION</u> type of optimisation
  - o 0 molecular dynamics
  - 1 quasi-Newton
  - o 2 Conjugate gradient
  - o 3 Damped MD
  - o etc
- NSW number of steps
- POTIM step in MD, fs

## Unit cell optimization

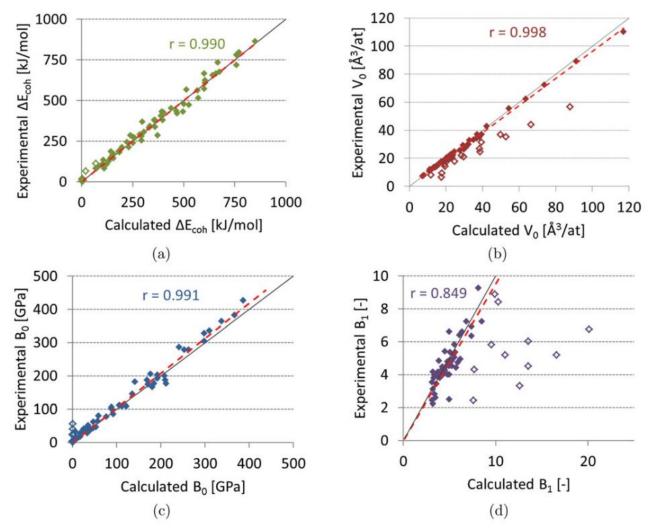
- Pulay stress: increase plane wave cutoff or do volume scan
- Use the same plane wave cutoff for different volumes
- Use consistent k-grids for different volumes

### In VASP ISIF:

- 2 only atoms
- 4 shape
- 3 shape and volume

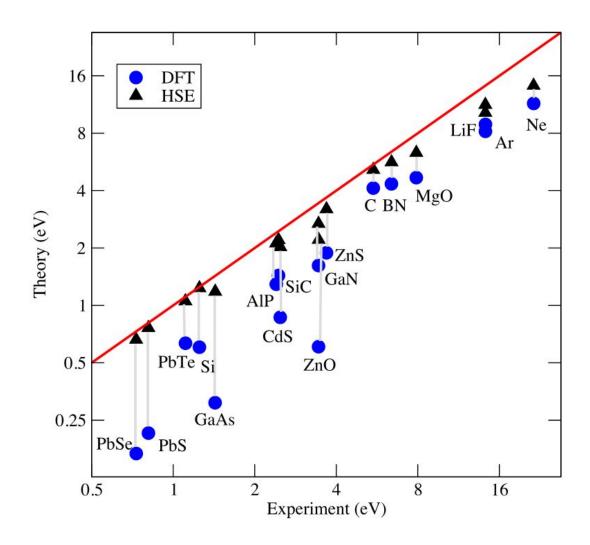


## Accuracy: geometry and elastic (PBE/PW91)



Geometry, cohesion energies, mechanical properties for elemental crystals are quite accurate even for simple DFT (LDA, PBE) from Lejaeghere *et al.*, *Crit. Rev. Solid State Mater. Sci. 39* (2014) 1-24; open symbols are excluded from the fit, see details in article

## **Accuracy:** band gap



For band gap calculations use HSE or GW methods, J. Hafner, *J. Phys.: Condens. Matter* 22 (2010) 384205

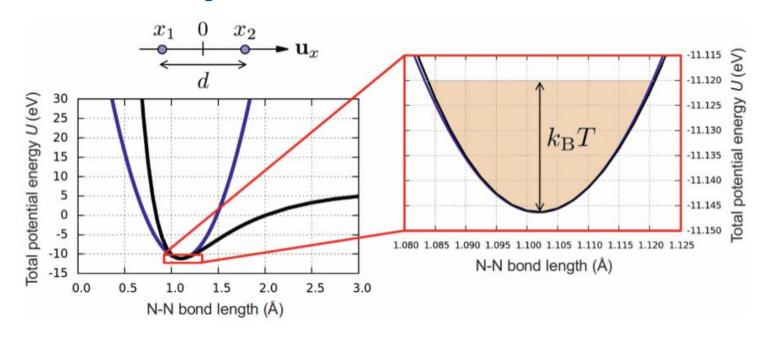
## Other things to keep in mind

- Kohn-Sham orbitals are supposed to give one-electron orbitals and approximation to elementary excitations
- Beyond DFT:
  - GW is good for excitations
  - DFT+U is a patch' for valence d- and f-electrons
  - CI/CC are conceptually challenging
  - QMC is technically challenging (sign' problem)
  - DMFT is computationally demanding
  - Overall, no reliable methods for strongly correlated systems (high-T superconductors, actinides)
- Surfaces and interfaces, 1D and 2D materials use appropriate supercell and k-grid along the reduced dimension

## Influence of temperature?

- thermal conductivity
- thermal expansion
- electrical resistivity
- heat capacity
- optical absorption
- superconductivity
- thermopower
- structural phase transitions.

### Vibrations in crystals



Taylor expansion in harmonic approximation

$$E = E_0 + \frac{1}{2} \sum_{i=1}^{3N} \sum_{j=1}^{3N} \left[ \frac{\partial^2 E}{\partial x_i \ \partial x_j} \right]_{\mathbf{x} = 0} x_i x_j$$

$$H_{ij} = \left[\frac{\partial^2 E}{\partial x_i \ \partial x_i}\right]_{==0} \qquad A_{ij} = H_{ij}/m_i$$

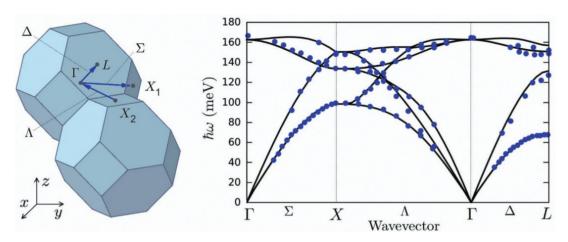
The eigenvalues of mass-weighted Hessian are called normal modes and have frequency  $\omega$ , 3N in total, where N is number of atoms

## The dependence on q (phonon wave vector)

But in periodic crystal the normal modes obey the Bloch theorem:

$$\mathbf{u}_n(\mathbf{R}) = \mathbf{u}_{n,q} e^{i\mathbf{q}\mathbf{R}}$$
 n - mode number

As a result normal modes got dispersion in **q** space



Vibrational spectra of diamond)

## **Thermodynamics**

Once phonon frequencies over Brillouin zone are known, the energy E of phonon system is given as

$$E = \sum_{\mathbf{q}j} \hbar \omega_{\mathbf{q}j} \left[ \frac{1}{2} + \frac{1}{\exp(\hbar \omega_{\mathbf{q}j}/k_{\mathrm{B}}T) - 1} \right],$$

Helmholtz free energy F:

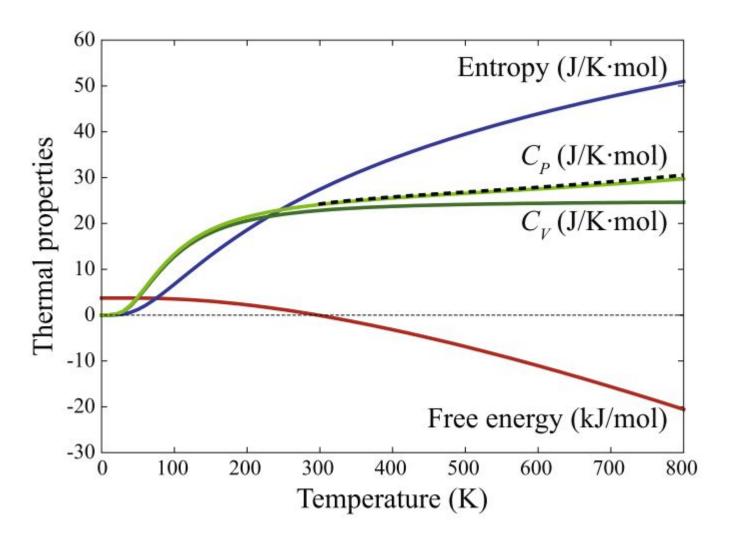
$$F = \frac{1}{2} \sum_{\mathbf{q}j} \hbar \omega_{\mathbf{q}j} + k_{\mathrm{B}} T \sum_{\mathbf{q}j} \ln \left[ 1 - \exp(-\hbar \omega_{\mathbf{q}j}/k_{\mathrm{B}} T) \right],$$

Entropy:

$$S = \frac{1}{2T} \sum_{\mathbf{q}j} \hbar \omega_{\mathbf{q}j} \coth \left[ \hbar \omega_{\mathbf{q}j} / 2k_{\mathrm{B}}T \right] - k_{\mathrm{B}} \sum_{\mathbf{q}j} \ln \left[ 2 \sinh (\hbar \omega_{\mathbf{q}j} / 2k_{\mathrm{B}}T) \right].$$

Atsushi Togo and Isao Tanaka, Scr. Mater., 108, 1-5 (2015)

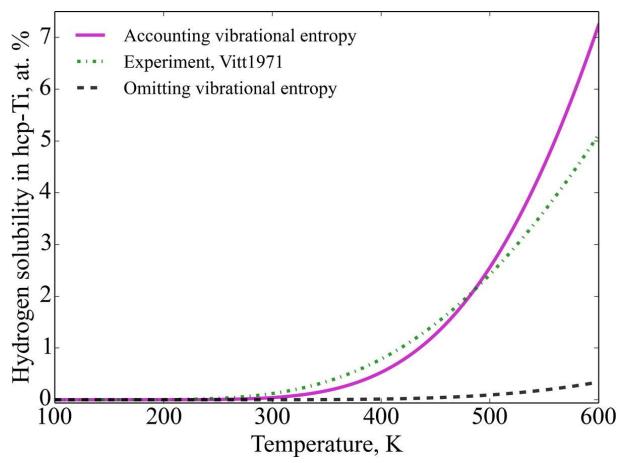
## **Thermodynamics**



Thermal properties of Aluminium

## Influence of vibrational entropy

#### Hydrogen solubility in Ti



Poletaev, D. O., et al. Computational Materials Science 114 (2016): 199-208.

### **Phonon Calculation**

- Two methods:
  - Finite differences creates a set of cell with small atom displacements.
    - IBRION = 5,6 in VASP
  - DFPT (Perturbation theory) primitive cell can be used
    - **■** <u>IBRION</u> = 7,8 in VASP
  - VASP calculates frequencies only at Gamma point!
    - For other points use Supercell
- To plot phonon band structure at other points and calculate thermodynamic properties use combination of DFT code and phonopy (<a href="http://atztogo.github.io/phono3py/vasp.html">http://atztogo.github.io/phono3py/vasp.html</a>)

## **Stability**

- Check stability of lattice by looking on frequencies
  - There should be no imaginary frequencies
  - Three translation modes
- Check mechanical stability
  - Eigenvalues of elastic tensor should be positive

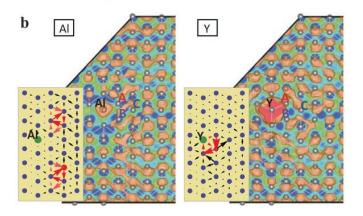
## **Calculation of Properties**

- Electronic structure
- Lattice constants
- Elastic moduli
- Phonon bands
- Free energy
- Phase diagrams
- Defects

### Methods vs scales

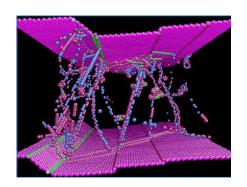
#### **Quantum methods**

- Schrödinger equation for atomic interaction
  - DFT (Density Functional Theory) and flavours
    - VASP, Abinit, QE, etc.
- Electronic structure
- Almost all properties!!!
- Restricted in system sizes (1000 atoms) and simulation time (1000 of steps per day)

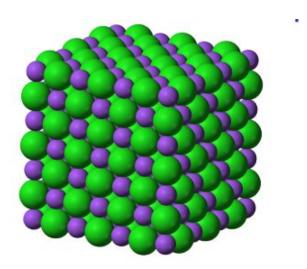


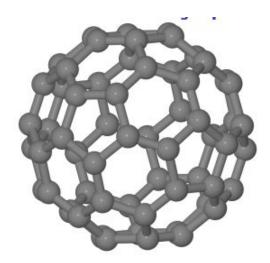
#### **Classical methods**

- The interaction between atoms described empirically:
  - pair potentials, force fields, (EAM) Embedded Atom Method
    - LAMMPS code
- Atomic dynamics
- 20x20x20 nm, nanoseconds
  - Radiation cascades
  - Diffusion phenomena
  - Phase transitions
  - Plastic deformation



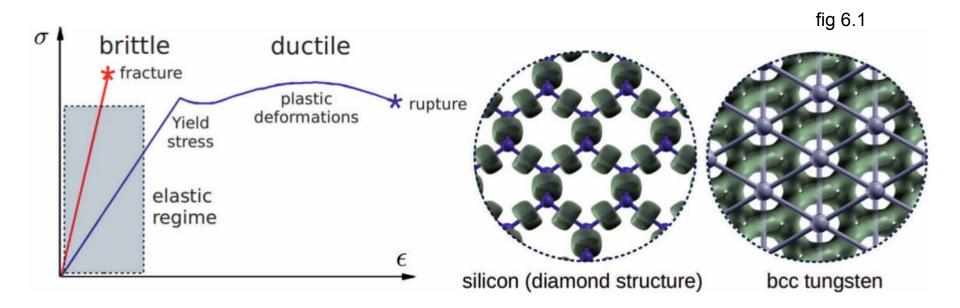
### Crystal vs molecule: computational chemistry perspective





- Brute force approach (large supercell or supermolecule) does not always work (e.g. metals) and is always inefficient (by orders of magnitude)
- Infinite symmetry due to translations (space group)
- Finite sums to lattice sums (or integrals)
- Essentially infinite system (thermodynamic limit) implies no exact answer like full CI + phase transitions (both classical and quantum)
- Metals (no molecular analogues)
- Nuclei motion breaks translation symmetry

## **Mechanical properties**



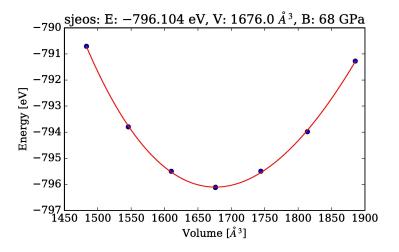
- The mechanical properties in brittle and ductile regimes depends on defects of crystal structure - an active research area for computational materials
- However, the elastic regime depends only on ideal crystal structure and can be easily described

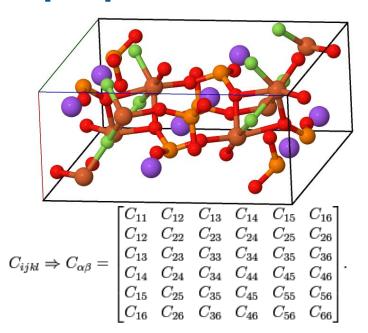
## **Equation of state and elastic properties**

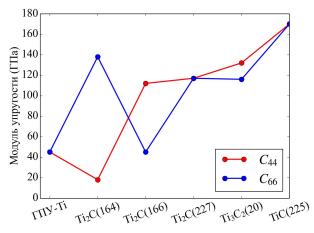
$$\mathbf{R} = \begin{pmatrix} & \frac{\sqrt{3}}{2} & & -\frac{1}{2} & & 0 \\ & 0 & & 1 & & 0 \\ & 0 & & 0 & & \frac{c}{a} \end{pmatrix}$$

$$\left(\begin{array}{cccc} 1 + \alpha & 0 & 0 \\ 0 & 1 - \alpha & 0 \\ 0 & 0 & 1 \end{array}\right)$$

$$E(V,\alpha) = E(V_0,0) + V_0[(\tau_1 - \tau_2)\alpha + (C_{11} - C_{12})\alpha^2].$$







D.Aksyonov et al, Computational Materials Science 65 (2012): 434-441

### **Elastic tensor notations**

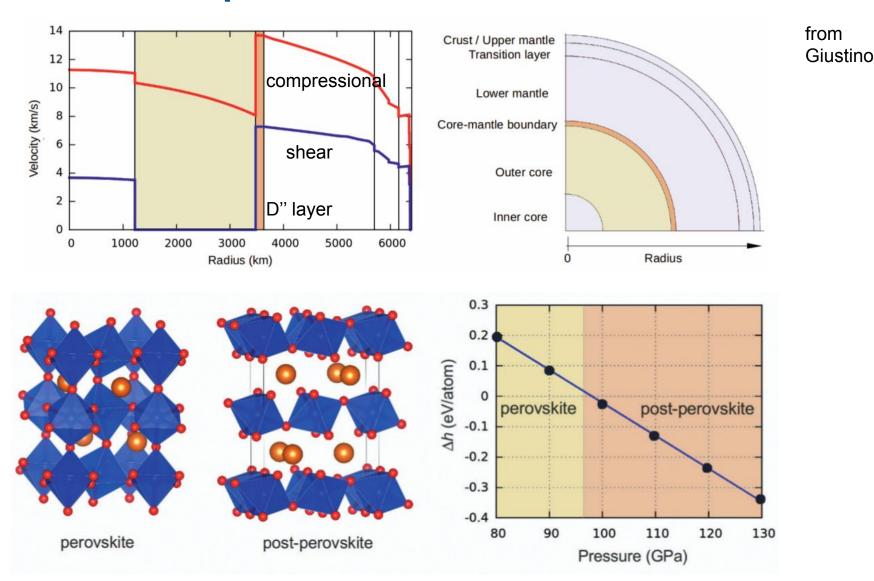
$$oldsymbol{\sigma} = egin{bmatrix} \sigma_{xx} & \sigma_{xy} & \sigma_{xz} \ \sigma_{yx} & \sigma_{yy} & \sigma_{yz} \ \sigma_{zx} & \sigma_{zy} & \sigma_{zz} \end{bmatrix} \qquad oldsymbol{\epsilon} = egin{bmatrix} \epsilon_{xx} & \epsilon_{xy} & \epsilon_{xz} \ \epsilon_{yx} & \epsilon_{yy} & \epsilon_{yz} \ \epsilon_{zx} & \epsilon_{zy} & \epsilon_{zz} \end{bmatrix}$$

In Voigt notation:

$$egin{aligned} ilde{\sigma} &= (\sigma_{xx}, \sigma_{yy}, \sigma_{zz}, \sigma_{yz}, \sigma_{xz}, \sigma_{xy}) \equiv (\sigma_1, \sigma_2, \sigma_3, \sigma_4, \sigma_5, \sigma_6) \ & ilde{\epsilon} &= (\epsilon_{xx}, \epsilon_{yy}, \epsilon_{zz}, \gamma_{yz}, \gamma_{xz}, \gamma_{xy}) \equiv (\epsilon_1, \epsilon_2, \epsilon_3, \epsilon_4, \epsilon_5, \epsilon_6) \end{aligned}$$

$$\sigma_{ij} = \sum_{k=1}^3 \sum_{l=1}^3 c_{ijkl} arepsilon_{kl} \quad ext{C}_{ ext{25}} = ext{C}_{ ext{yyxz}} ext{ gives relationship between } e_{ ext{xz}} \ ext{deformation component } \sigma_{ ext{yy}} ext{ stress component }$$

## Influence of pressure



A.Oganov, S. Ono, Nature 430.6998 (2004): 445-448

## Temperature-pressure phase diagram

Giustino fig 8.8

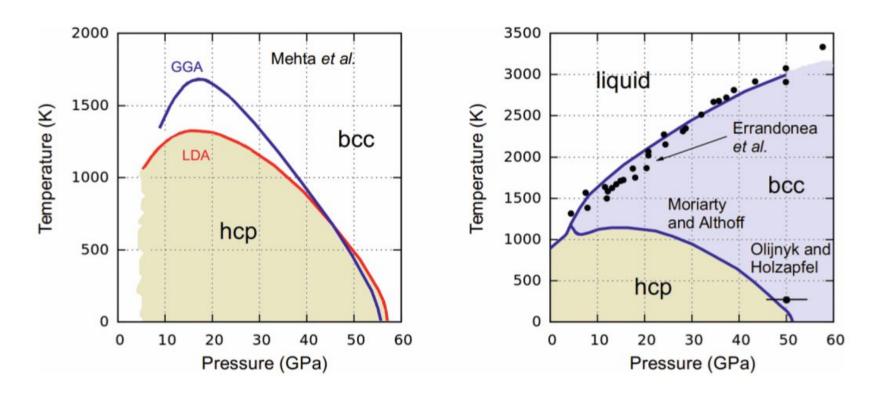


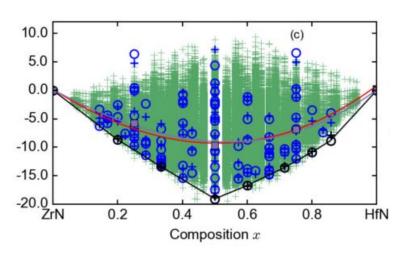
Fig. 8.8 The phase diagram of Mg from first principles. The left panel shows the calculations

## Temperature-chemical phase diagrams

### More complicated:

- 1) Find all phases in chemical space for example with USPEX code
- Study solid solutions use cluster expansion method (ATAT) and Monte-Carlo
- 3) Study the influence of temperature by making phonon calculations
- 4) Plot phase diagrams

DFT and cluster expansion, ZrN-HfN



J. Phys.: Condens. Matter 29 (2017) 035401

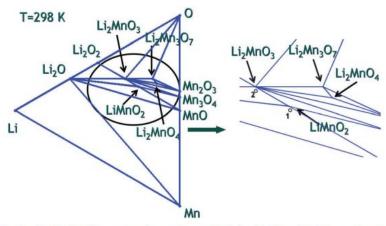
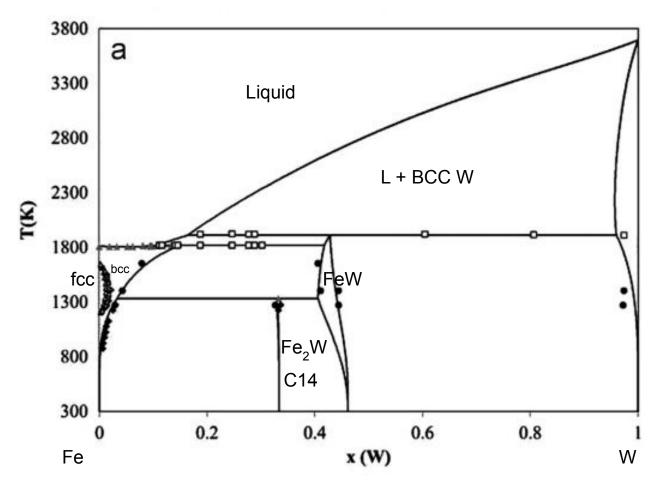


Fig. 4 Calculated ternary phase diagram of the Li-Mn-O system at room temperature. Points 1 and 2 show the position of the Li-O vacancy pair for LiMnO<sub>2</sub> and Li<sub>2</sub>MnO<sub>3</sub>, respectively (see the text for details).

Longo Phys. Chem. Chem. Phys., 2014, 16, 11218

## Case study Fe–W phase diagram from DFT



- DFT
- phonon calculations
- Calphad

A. Jacob, et al., CALPHAD: Computer Coupling of Phase Diagrams and Thermochemistry 50 (2015) 92–104

$$\begin{split} G^{C14} &= y_{Fe}^1 y_W^2 \, G_{Fe:W}^0 + y_W^1 y_{Fe}^2 G_{W:Fe}^0 + y_W^1 y_W^2 G_{W:W}^0 + \\ & y_{Fe}^1 y_{Fe}^2 G_{Fe:Fe}^0 \\ & + RT \bigg[ 2 \Big( y_{Fe}^1 \text{ln} y_{Fe}^1 + y_W^1 \text{ln} y_W^1 \Big) + \Big( y_{Fe}^2 \text{ln} y_{Fe}^2 + y_W^2 \text{ln} y_W^2 \Big) \bigg] \end{split}$$

## **Summary**

#### Main definitions

- Bands single particle solutions
- K-points integration grid in 1st Brillouin zone
- Partial occupation of bands (smearing)
- Plane wave basis set wave function represented on reciprocal space grid within cut-off
- Supercells approximating aperiodic system with a periodic one

### **Principles**

- Convergence with respect to basis set, k-points, smearing, supercell
- Compare only results obtained with the same setups

### **Discussion**

- Why do we need smearing of bands?
- What is the physical meaning of energy cut-off?

- What is pseudopotential and why it used?
- The k-grid is 12x12x12 for a cubic unit cell. What is an equivalent k-grid for 3x2x1 supercell?

### **Discussion**

- What convergence tests should be performed in DFT calculations for periodic systems?
- How to estimate dynamical and mechanical stability of the lattice?

 Which class of materials requires less k-points: metals or insulators? Why?

### **Individual studies:**

Reading

Required: Giustino (9.1-9.2, 9.4-9.5, 6.1-6.4, 7.1-7.4, 8.2-8.4)

Additional: Sholl (Ch.3)

- 1. **F. Giustino**, Materials Modelling using Density Functional Theory, Oxford, 2014
- 2. **D. Sholl**, Density functional theory A Practical Introduction, New Jersey, Wiley, 2009

# Thank you for your attention!